

DMTH10H038SPDW 100V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	RDS(ON) max	l _D max Tc = +25°C
100V	33mΩ @ V _{GS} = 10V	25A

Description and Applications

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

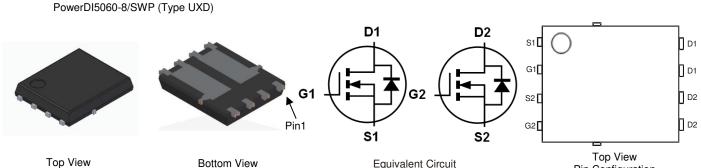
- **DC-DC** converters
- Motors

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Additional Tin-Plated on Sidewall Pads for Optical Solder Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Pin Configuration

Ordering Information (Note 4)

Part Number	Pookago	Packing		
Part Number	Package	Qty.	Carrier	
DMTH10H038SPDW-13	PowerDI5060-8/SWP (Type UXD)	2500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

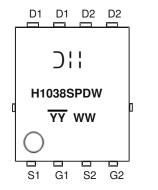
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



Characteria Control Contro H1038SPDW = Product Type Marking Code $\overrightarrow{YY}WW = Date Code Marking$ $<math>\overrightarrow{YY} = Year (ex: 22 = 2022)$ WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	100	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 5)	Tc = +25°C Tc = +100°C	١D	25 18	А
Maximum Body Diode Forward Current	ls	25	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	100	A	
Pulsed Body Diode Forward Current (10µs Pulse, Tc=+25°C, Package Li	lsм	100	A	
Avalanche Current, L = 0.3mH	las	12.5	A	
Avalanche Energy, L = 0.3mH	E _{AS}	23.4	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Thermal Resistance, Junction to Ambient (Note 6)		R _{0JA}	55	°C/W
Total Power Dissipation	T _A = +25°C	PD	2.7	W
Thermal Resistance, Junction to Case (Note 5)	•	Rejc	3.8	°C/W
Total Power Dissipation	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	39	W
Operating and Storage Temperature Range	•	TJ, TSTG	-55 to +175	°C

Notes:

Thermal resistance from junction to solder point (on the exposed drain pin).
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.



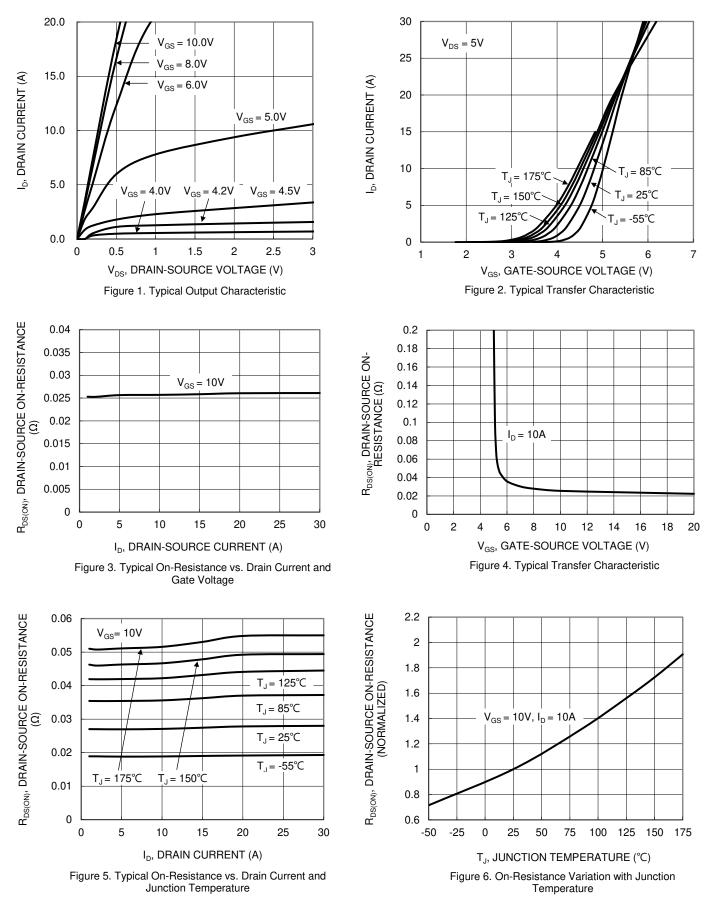
Electrical Characteristics (@T_C = +25°C, unless otherwise specified.)

Characteristic	Cumphal	Min	Turn	Max	Unit	Test Condition
	Symbol	IVIIN	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	100	—	—	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						·
Gate Threshold Voltage	VGS(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	25	33	mΩ	$V_{GS} = 10V, I_D = 10A$
Diode Forward Voltage	V _{SD}	_	0.9	1	V	$V_{GS} = 0V, I_{S} = 10A$
DYNAMIC CHARACTERISTICS (Note 8)						·
Input Capacitance	Ciss	—	544	—	pF	
Output Capacitance	Coss	—	181		pF	−VDS = 50V, VGS = 0V −f = 1MHz
Reverse Transfer Capacitance	Crss	—	6.0		pF	
Gate Resistance	Rg	—	1.2		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	4.3	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	—	8.0		nC	
Gate-Source Charge	Qgs	—	1.8		nC	$V_{DS} = 50V, I_D = 7A$
Gate-Drain Charge	Qgd	—	2.4		nC	
Turn-On Delay Time	td(on)	—	8.5		ns	
Turn-On Rise Time	tR	—	2.7		ns	V _{DS} = 50V, I _D = 7A
Turn-Off Delay Time	t _{D(OFF)}	—	11.9	_	ns	$V_{GS} = 10V, R_{GEN} = 6\Omega$
Turn-Off Fall Time	tF	_	6.2	_	ns	
Reverse Recovery Time	trr	_	33.2	_	ns	I _F = 7A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}	—	34.3	_	nC	$IF = 7A$, $u/ul = 100A/\mu s$

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.



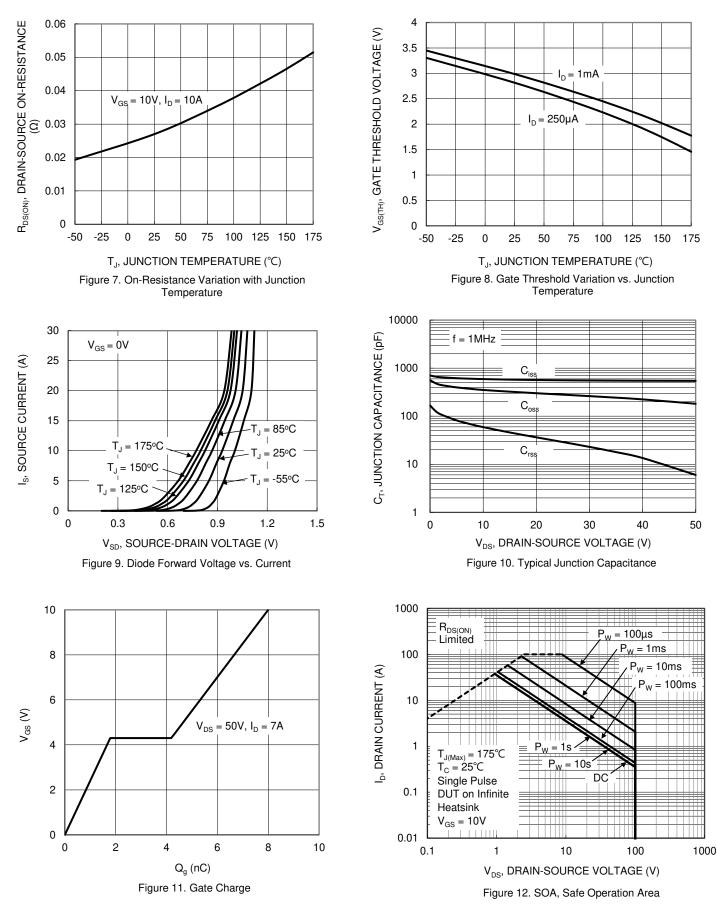
DMTH10H038SPDW



DMTH10H038SPDW Document number: DS44054 Rev. 2 - 2 March 2022 © Diodes Incorporated

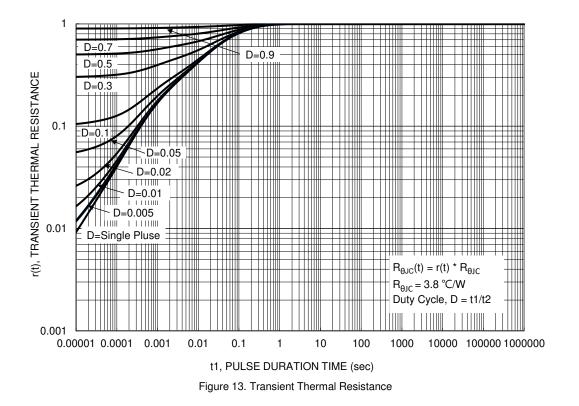


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PowerDI5060-8/SWP

(Type UXD)

Max

1.10

0.05

0.50

0.35

0.25REF

0.230 0.330 0.277

5.15 BS

5.10

1.66

4.18

3.86

4.595

0.400

4.005

0.225

12°

8°

1.27BS0

6.40 BS

5.60 6.00

0.635 0.835

0.635 0.835

All Dimensions in mm

Тур

1.00

0.41

0.25

4.90

1.55

3.98

5.80

3.66

4.395

0.735

0.735

0.300

3.605

0.125

11°

7°

Min

0.90

0.00

0.30

0.20

4.70

1.46

3.78

3.46

4.195

1.05

0.200

3.205

0.025

10°

6°

Dim

Α

A1

b

b2

b4

С

D D1

D2

D3

Ε

E1

E2

E2a

e k

L

La

L1 M

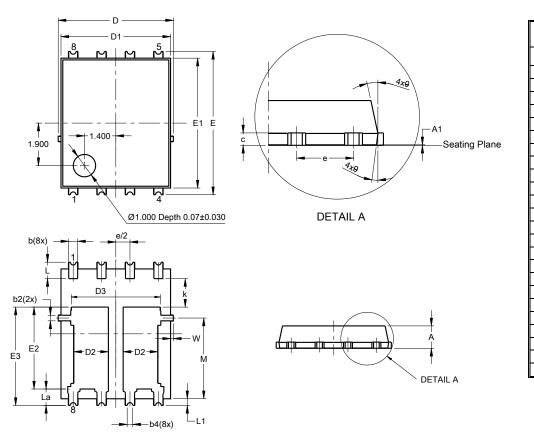
W

θ

θ1

Package Outline Dimensions

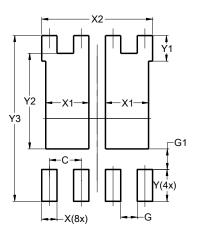
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UXD)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UXD)

Dimensions	Value			
Dimensions	(in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	1.720			
X2	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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